ACE2370M

N-Channel 100-V MOSFET

Description

ACE2370M uses advanced trench technology to provide excellent $R_{DS(ON)}$.

This device particularly suits for low voltage application such as power management of desktop computer or notebook computer power management, DC/DC converter.

Features

- Low $r_{DS(on)}$ trench technology
- Low thermal impedance
- Fast switching speed

Applications:

- PoE Power Sourcing Equipment
- PoE Powered Devices
- Telecom DC/DC converters
- White LED boost converters

Absolute Maximum Ratings

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V_{DS}	100	V
Gate-Source Voltage		V_{GS}	±20	
Continuous Drain Current[a]	T_A=25℃	I_D	1.5	A
	T_A=70℃		1.2	
Pulsed Drain Current [b]		I_{DM}	10	
Continuous Source Current (Diode Conduction) [a]		I_S	1.6	A
Power Dissipation[a]	T_A=25℃	P_D	1.3	W
	T_A=70℃		0.8	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 150	°C

THERMAL RESISTANCE RATINGS

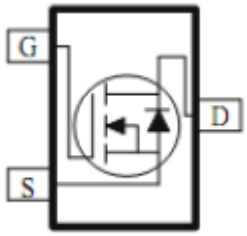
Parameter		Symbol	Maximum	Unit
Maximum Junction-to-Ambient [a]	t<=10sec	$R_{\theta JA}$	100	℃/W
	Steady State		166	

Notes

a. Surface Mounted on 1” x 1” FR4 Board.

b. Pulse width limited by maximum junction temperature

Packaging Type



Ordering information

ACE2370M BM + H

- H : Halogen - free
- + : Pb - free
- BM : SOT-23-3

Electrical Characteristics

T_A=25°C, unless otherwise specified.

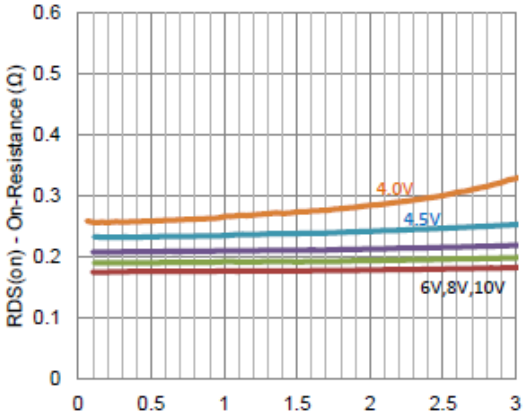
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 uA	1			V
Gate-Body Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = 20 V			±100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 80 V, V_{GS} = 0 V			1	uA
		V_{DS} = 80V, V_{GS} = 0 V, T_J = 55°C			10	
On-State Drain Current	$I_{D(on)}$	V_{DS} = 5 V, V_{GS} = 10 V	4			A
Drain-Source On-Resistance	$r_{DS(on)}$	V_{GS} = 10 V, I_D = 1.2 A			280	mΩ
		V_{GS} = 4.5 V, I_D = 1.0 A			355	
Forward Transconductance	g_{fs}	V_{DS} = 15 V, I_D = 1.2 A		5		S
Diode Forward Voltage	V_{SD}	I_S = 0.8 A, V_{GS} = 0 V		0.75		V
Dynamic						
Total Gate Charge	Q_g	V_{DS} = 50 V, V_{GS} = 4.5 V, I_D = 1.2 A		3.9		nC
Gate-Source Charge	Q_{gs}			1.3		
Gate-Drain Charge	Q_{gd}			2.0		
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = 50 V, R_L = 41.7 Ω , I_D = 1.2 A, V_{GEN} = 10 V, R_{GEN} = 6 Ω		4.8		nS
Rise Time	t_r			3.9		
Turn-Off Delay Time	$t_{d(off)}$			12.7		
Fall Time	t_f			3.2		
Input Capacitance	C_{iss}	V_{DS} = 15 V, V_{GS} = 0 V, f =1 MHz		332		pF
Output Capacitance	C_{oss}			40		
ReverseTransfer Capacitance	C_{rss}			29		
Gate Resistance	R_g	f =1 MHz		0.3		Ω

Note:

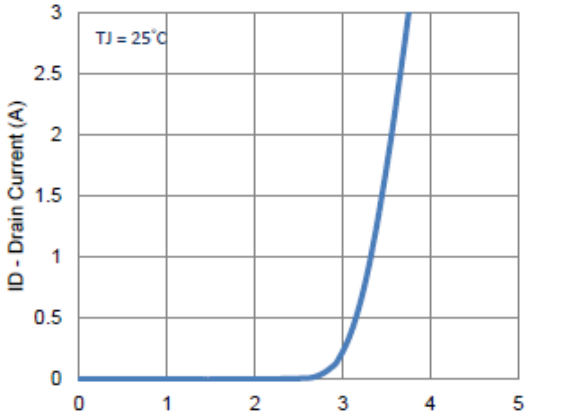
a. Pulse test: PW <= 300us duty cycle <= 2%.

b. Guaranteed by design, not subject to production testing.

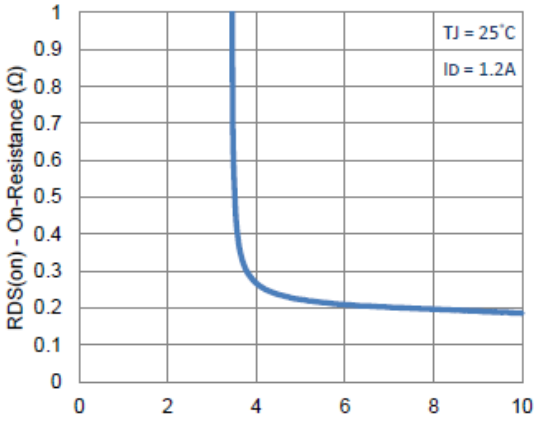
Typical Performance Characteristics (N-Channel)



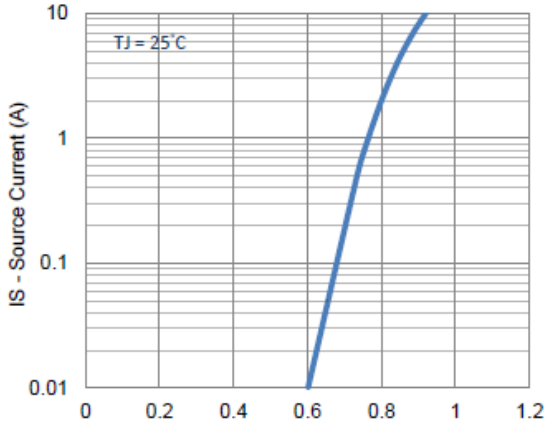
1. On-Resistance vs. Drain Current



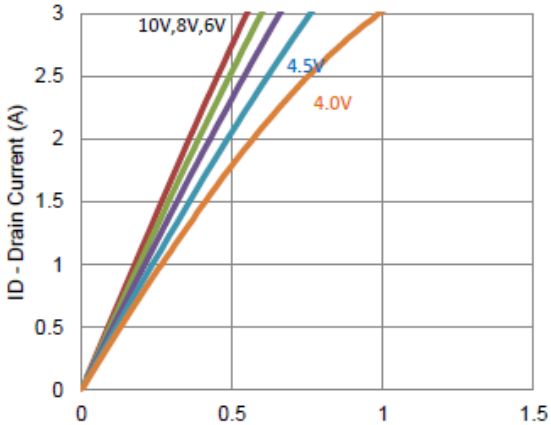
2. Transfer Characteristics



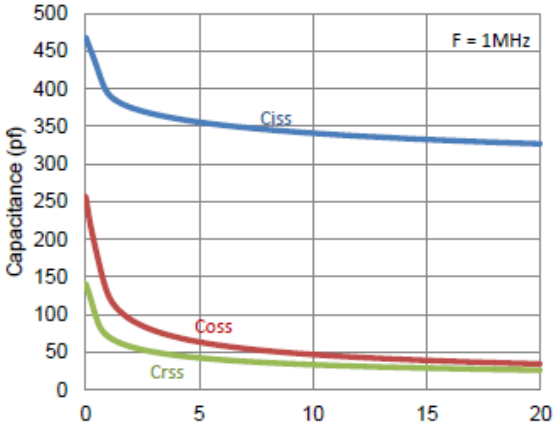
3. On-Resistance vs. Gate-to-Source Voltage



4. Drain-to-Source Forward Voltage

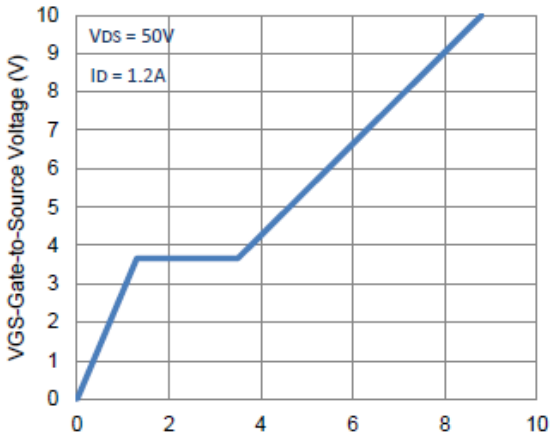


5. Output Characteristics

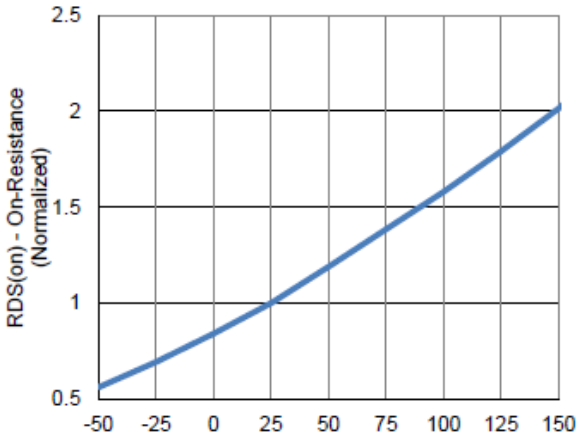


6. Capacitance

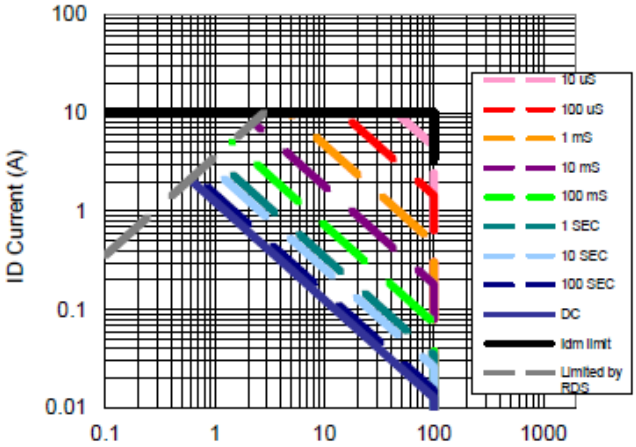
Typical Performance Characteristics



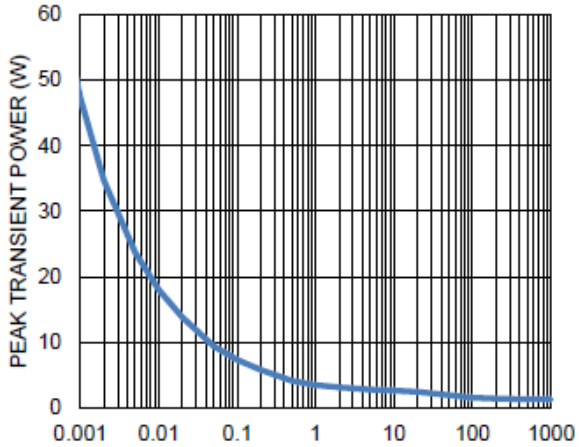
7. Gate Charge



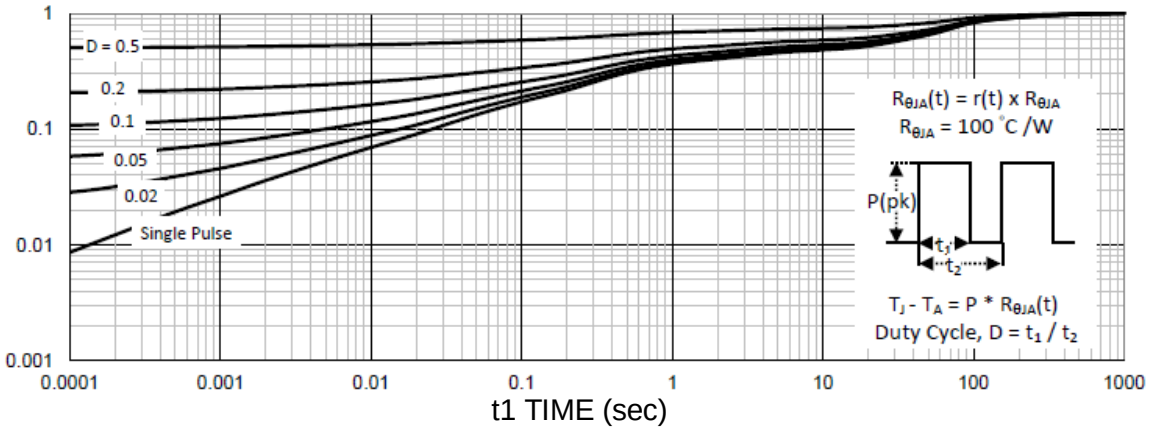
8. Normalized On-Resistance Vs Junction Temperature



9. Safe Operating Area



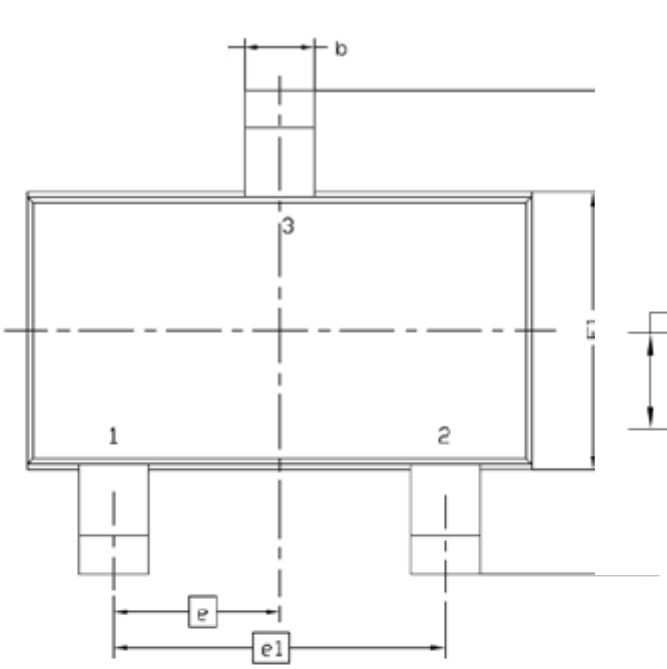
10. Single Pulse Maximum Power Dissipation

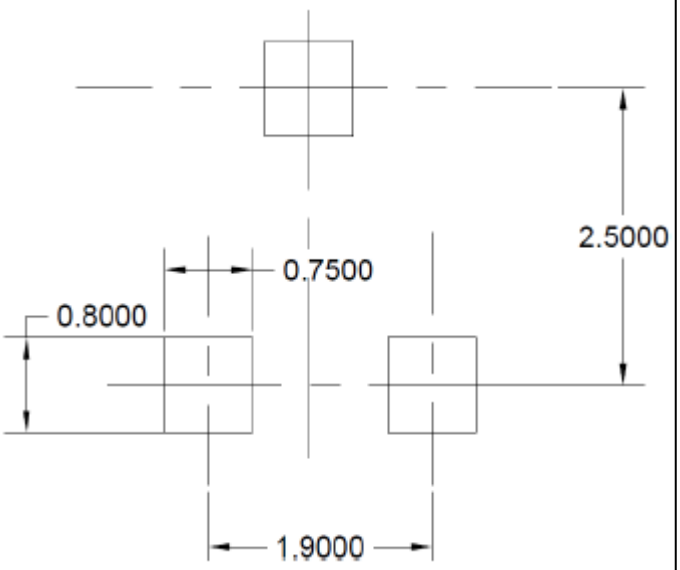


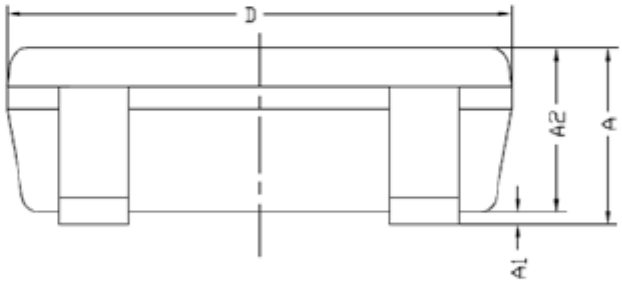
11. Normalized Thermal Transient Junction to Ambient

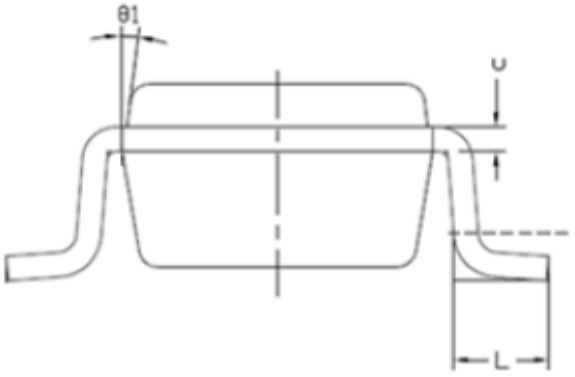
Packing Information

STO-23-3









SYMBOL	MILLIMETERS	
	MIN	MAX
A	0.8	1.2
A1	0	0.1
A2	0.7	1.1
b	0.3	0.5
c	0.1	0.2
D	2.7	3.1
E	2.6	3
E1	1.4	1.8
e	0.95 BSC	
e1	1.9 BSC	
L	0.3	0.6
θ1	7 ◦ NOM	

Recommended Pad Layout

Note: Drain opening is recommended to be solder mask defined in a copper fill to provide improved thermal performance.

Notes

ACE does not assume any responsibility for use as critical components in life support devices or systems without the express written approval of the president and general counsel of ACE Electronics Co., LTD. As sued herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and shoes failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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